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# Contents

|           |                                                            |    |
|-----------|------------------------------------------------------------|----|
| <b>16</b> | <b>Free-Electron Model of Metals</b> . . . . .             | 1  |
| 16.1      | Classical Drude Model . . . . .                            | 2  |
| 16.1.1    | Basic Assumptions of the Model . . . . .                   | 2  |
| 16.1.2    | Electrical Conductivity . . . . .                          | 5  |
| 16.1.3    | Heat Conduction . . . . .                                  | 9  |
| 16.1.4    | Hall Resistance . . . . .                                  | 11 |
| 16.1.5    | AC Conductivity . . . . .                                  | 14 |
| 16.1.6    | High-Frequency Behavior of a Classical Electron Gas . .    | 16 |
| 16.1.7    | Magnetic Properties . . . . .                              | 20 |
| 16.1.8    | Failures of the Drude Model . . . . .                      | 22 |
| 16.2      | Quantum Mechanical Sommerfeld Model . . . . .              | 24 |
| 16.2.1    | Quantum Mechanical States of Free Electrons . . . . .      | 24 |
| 16.2.2    | Ground State of the Electron Gas . . . . .                 | 28 |
| 16.2.3    | Excited Electron and Hole States . . . . .                 | 31 |
| 16.2.4    | Density of States of the Electron Gas . . . . .            | 32 |
| 16.2.5    | Ideal Electron Gas at Finite Temperatures . . . . .        | 34 |
| 16.2.6    | Sommerfeld Expansion . . . . .                             | 37 |
| 16.2.7    | Specific Heat of the Electron Gas . . . . .                | 40 |
| 16.2.8    | Equation of State for the Ideal Electron Gas . . . . .     | 42 |
| 16.2.9    | Susceptibility of the Electron Gas . . . . .               | 44 |
| 16.3      | Electric and Heat Currents in an Electron Gas . . . . .    | 47 |
| 16.3.1    | Noninteracting Electrons in a Uniform Electric Field . . . | 47 |
| 16.3.2    | Stationary Distribution Function . . . . .                 | 49 |
| 16.3.3    | Electric and Heat Currents . . . . .                       | 53 |
| 16.3.4    | Thermoelectric Phenomena . . . . .                         | 56 |
| 16.3.5    | Galvanomagnetic and Thermomagnetic Phenomena . . . .       | 61 |
| 16.4      | Scattering of Free Electrons by Impurities . . . . .       | 64 |
| 16.4.1    | Formal Solution of the Schrödinger Equation . . . . .      | 64 |
| 16.4.2    | Approach Based on Scattering Theory . . . . .              | 65 |
| 16.4.3    | Friedel Oscillations Around Impurities . . . . .           | 69 |
| 16.4.4    | Bound States Around Impurities . . . . .                   | 73 |
| 16.5      | Inadequacies of the Free-Electron Model . . . . .          | 74 |

|           |                                                                           |     |
|-----------|---------------------------------------------------------------------------|-----|
| <b>17</b> | <b>Electrons in the Periodic Potential of a Crystal</b> . . . . .         | 77  |
| 17.1      | Band Structure of Electronic States . . . . .                             | 78  |
| 17.1.1    | Bloch States . . . . .                                                    | 78  |
| 17.1.2    | Energy Levels of Bloch States . . . . .                                   | 80  |
| 17.1.3    | Eigenvalue Problem for Equivalent $\mathbf{k}$ Vectors . . . . .          | 82  |
| 17.1.4    | Role of the Spin–Orbit Interaction . . . . .                              | 83  |
| 17.2      | Representation of the Band Structure . . . . .                            | 84  |
| 17.2.1    | Reduced-, Repeated-, and Extended-Zone Schemes . . . . .                  | 85  |
| 17.2.2    | Constant-Energy Surfaces and the Fermi Surface . . . . .                  | 88  |
| 17.3      | Metals, Insulators, Semiconductors . . . . .                              | 89  |
| 17.4      | Bloch Electrons as Quasiparticles . . . . .                               | 92  |
| 17.4.1    | Creation and Annihilation Operators of Bloch States . . . . .             | 92  |
| 17.4.2    | Effective Mass of Bloch Electrons . . . . .                               | 93  |
| 17.4.3    | Bloch Electrons and Holes . . . . .                                       | 95  |
| 17.4.4    | Density of States for Bloch Electrons . . . . .                           | 96  |
| 17.4.5    | Specific Heat and Susceptibility of Bloch Electrons . . . . .             | 98  |
| 17.5      | Wannier States . . . . .                                                  | 100 |
| 17.5.1    | Wannier Functions . . . . .                                               | 100 |
| 17.5.2    | Creation and Annihilation Operators of Wannier States . . . . .           | 103 |
| 17.6      | Electron States Around Impurities . . . . .                               | 104 |
| <b>18</b> | <b>Simple Models of the Band Structure</b> . . . . .                      | 109 |
| 18.1      | Nearly-Free-Electron Approximation . . . . .                              | 109 |
| 18.1.1    | Band Structure in the Empty Lattice . . . . .                             | 110 |
| 18.1.2    | Fermi Surface in the Empty Lattice . . . . .                              | 115 |
| 18.1.3    | Effects of a Weak Periodic Potential . . . . .                            | 120 |
| 18.1.4    | Lifting of Accidental Degeneracies . . . . .                              | 126 |
| 18.1.5    | Fermi Surface for Nearly Free Electrons . . . . .                         | 136 |
| 18.2      | Tight-Binding Approximation . . . . .                                     | 139 |
| 18.2.1    | Broadening of Atomic Levels into Bands . . . . .                          | 140 |
| 18.2.2    | Band of $s$ -Electrons . . . . .                                          | 143 |
| 18.2.3    | Band of $p$ -Electrons . . . . .                                          | 145 |
| <b>19</b> | <b>Methods for Calculating and Measuring the Band Structure</b> . . . . . | 151 |
| 19.1      | Matrix Methods . . . . .                                                  | 152 |
| 19.1.1    | General Formulation of the Problem . . . . .                              | 152 |
| 19.1.2    | LCAO Method . . . . .                                                     | 154 |
| 19.1.3    | Plane-Wave Method . . . . .                                               | 156 |
| 19.1.4    | Orthogonalized-Plane-Wave Method . . . . .                                | 157 |
| 19.1.5    | Pseudopotential Method . . . . .                                          | 160 |
| 19.2      | Variational Methods and Methods Based on Scattering Theory . . . . .      | 164 |
| 19.2.1    | Augmented-Plane-Wave Method . . . . .                                     | 164 |
| 19.2.2    | Green Function or KKR Method . . . . .                                    | 168 |
| 19.2.3    | Physical Interpretation of the KKR Method . . . . .                       | 173 |

|           |                                                           |            |
|-----------|-----------------------------------------------------------|------------|
| 19.2.4    | LMTO Method                                               | 175        |
| 19.3      | Band Structure and Fermi Surface of Simple Metals         | 178        |
| 19.3.1    | Monovalent Metals                                         | 178        |
| 19.3.2    | Divalent Metals                                           | 182        |
| 19.3.3    | Trivalent Metals                                          | 183        |
| 19.3.4    | Tetravalent Elements                                      | 185        |
| 19.3.5    | Band Structure of Transition Metals and Rare-Earth Metals | 185        |
| 19.4      | Experimental Study of the Band Structure                  | 187        |
| 19.4.1    | Positron Annihilation and Compton Scattering              | 187        |
| 19.4.2    | Photoelectron Spectroscopy                                | 190        |
| <b>20</b> | <b>Electronic Structure of Semiconductors</b>             | <b>195</b> |
| 20.1      | Semiconductor Materials                                   | 196        |
| 20.1.1    | Elemental Semiconductors                                  | 196        |
| 20.1.2    | Compound Semiconductors                                   | 198        |
| 20.2      | Band Structure of Pure Semiconductors                     | 201        |
| 20.2.1    | Electronic Structure in the Diamond Lattice               | 201        |
| 20.2.2    | Band Structure of Silicon                                 | 204        |
| 20.2.3    | Band Structure of Germanium                               | 206        |
| 20.2.4    | Band Structure of Compound Semiconductors                 | 208        |
| 20.2.5    | Indirect- and Direct-Gap Semiconductors                   | 211        |
| 20.3      | Electrons and Holes in Intrinsic Semiconductors           | 212        |
| 20.3.1    | Number of Thermally Excited Charge Carriers               | 212        |
| 20.3.2    | Temperature Dependence of the Chemical Potential          | 218        |
| 20.4      | Electronic Structure of Doped Semiconductors              | 219        |
| 20.4.1    | Energy of Donor and Acceptor Levels                       | 220        |
| 20.5      | Doped Semiconductors at Finite Temperatures               | 224        |
| 20.5.1    | Condition of Charge Neutrality                            | 225        |
| 20.5.2    | Thermal Population of Donor and Acceptor Levels           | 227        |
| 20.5.3    | Number of Carriers in Doped Semiconductors                | 228        |
| <b>21</b> | <b>Semiclassical Dynamics of Electrons</b>                | <b>239</b> |
| 21.1      | Basics of Semiclassical Dynamics                          | 239        |
| 21.1.1    | Velocity of Bloch Electrons                               | 240        |
| 21.1.2    | Semiclassical Equation of Motion                          | 243        |
| 21.1.3    | Effective-Mass Tensor                                     | 246        |
| 21.1.4    | Motion of Electrons and Holes                             | 247        |
| 21.2      | Bloch Electrons in Uniform Magnetic Fields                | 248        |
| 21.2.1    | Motion in Reciprocal and Real Spaces                      | 249        |
| 21.2.2    | Open and Closed Orbits in Magnetic Fields                 | 251        |
| 21.2.3    | Cyclotron Frequency in a Closed Orbit                     | 253        |
| 21.2.4    | Cyclotron Mass                                            | 255        |
| 21.2.5    | Cyclotron Resonance                                       | 259        |
| 21.2.6    | Azbel–Kaner Resonance                                     | 262        |

|           |                                                                             |            |
|-----------|-----------------------------------------------------------------------------|------------|
| 21.2.7    | Magnetoacoustic Geometric Oscillations . . . . .                            | 265        |
| 21.3      | Size Effects . . . . .                                                      | 268        |
| 21.3.1    | Extinction of the Resonance in Thin Samples . . . . .                       | 268        |
| 21.3.2    | Radiofrequency Size Effect . . . . .                                        | 270        |
| 21.4      | Limitations of the Semiclassical Description . . . . .                      | 271        |
| 21.4.1    | Conditions of the Applicability of Semiclassical<br>Dynamics . . . . .      | 272        |
| 21.4.2    | Electric and Magnetic Breakdown . . . . .                                   | 274        |
| <b>22</b> | <b>Electrons in Strong Magnetic Fields . . . . .</b>                        | <b>277</b> |
| 22.1      | Free Electrons in a Magnetic Field . . . . .                                | 277        |
| 22.1.1    | One-Particle Energy Spectrum . . . . .                                      | 277        |
| 22.1.2    | Degree of Degeneracy of Landau Levels . . . . .                             | 281        |
| 22.1.3    | Density of States . . . . .                                                 | 283        |
| 22.1.4    | Visualization of the Landau States . . . . .                                | 288        |
| 22.1.5    | Landau States in the Symmetric Gauge . . . . .                              | 290        |
| 22.1.6    | Edge States . . . . .                                                       | 294        |
| 22.2      | Landau Diamagnetism . . . . .                                               | 295        |
| 22.3      | Bloch Electrons in Strong Magnetic Fields . . . . .                         | 297        |
| 22.3.1    | Electrons Characterized by an Effective-Mass Tensor . . . . .               | 297        |
| 22.3.2    | Semiclassical Quantization . . . . .                                        | 300        |
| 22.3.3    | Quantization of the Orbit in Real Space . . . . .                           | 301        |
| 22.3.4    | Energy Spectrum in the Tight-Binding Approximation . . . . .                | 302        |
| 22.3.5    | Diamagnetic Susceptibility of Bloch Electrons . . . . .                     | 305        |
| 22.4      | Quantum Oscillations in Magnetic Fields . . . . .                           | 306        |
| 22.4.1    | Oscillations in a Two-Dimensional Electron Gas . . . . .                    | 307        |
| 22.4.2    | Energy of a Three-Dimensional Electron Gas<br>in a Magnetic Field . . . . . | 310        |
| 22.4.3    | De Haas–van Alphen Effect . . . . .                                         | 314        |
| 22.4.4    | Role of Spin in Oscillatory Phenomena . . . . .                             | 317        |
| 22.4.5    | Oscillations in the Magnetization at Finite<br>Temperatures . . . . .       | 318        |
| 22.4.6    | Oscillations for General Fermi Surfaces . . . . .                           | 324        |
| 22.4.7    | Experimental Results . . . . .                                              | 325        |
| 22.4.8    | Further Oscillation Phenomena . . . . .                                     | 327        |
| <b>23</b> | <b>Electrons in Thermally Vibrating Lattices . . . . .</b>                  | <b>329</b> |
| 23.1      | Adiabatic Decoupling . . . . .                                              | 330        |
| 23.2      | Hamiltonian of the Electron–Phonon Interaction . . . . .                    | 333        |
| 23.2.1    | Second-Quantized Form of the Hamiltonian . . . . .                          | 334        |
| 23.2.2    | Electron–Phonon Matrix Element . . . . .                                    | 337        |
| 23.2.3    | Deformation Potential . . . . .                                             | 339        |
| 23.2.4    | Interaction of Electrons with Optical Phonons . . . . .                     | 341        |
| 23.3      | Consequences of the Electron–Phonon Interaction . . . . .                   | 343        |
| 23.3.1    | Finite Lifetime of Electron States . . . . .                                | 344        |

|           |                                                                  |            |
|-----------|------------------------------------------------------------------|------------|
| 23.3.2    | Polarons                                                         | 346        |
| 23.3.3    | Kohn Anomaly and Peierls Instability                             | 350        |
| 23.3.4    | Jahn–Teller Distortion                                           | 353        |
| 23.3.5    | Effective Electron–Electron Interaction                          | 355        |
| <b>24</b> | <b>Transport Phenomena</b>                                       | <b>357</b> |
| 24.1      | General Formulation of Transport Phenomena                       | 358        |
| 24.1.1    | Currents and Driving Forces                                      | 359        |
| 24.1.2    | Onsager Relations                                                | 360        |
| 24.2      | Boltzmann Equation                                               | 361        |
| 24.2.1    | Nonequilibrium Distribution Function                             | 362        |
| 24.2.2    | Boltzmann Equation for Electrons                                 | 363        |
| 24.2.3    | Collision Term for Scattering by Lattice Defects                 | 365        |
| 24.2.4    | Boltzmann Equation for Phonons                                   | 366        |
| 24.2.5    | Coupled Electron–Phonon Systems                                  | 368        |
| 24.3      | Relaxation-Time Approximation                                    | 370        |
| 24.3.1    | Relaxation Time                                                  | 370        |
| 24.3.2    | Distribution Function in the Relaxation-Time<br>Approximation    | 373        |
| 24.3.3    | DC Conductivity                                                  | 376        |
| 24.3.4    | AC and Optical Conductivity                                      | 378        |
| 24.3.5    | General Form of Transport Coefficients                           | 379        |
| 24.3.6    | Hall Effect                                                      | 381        |
| 24.3.7    | Alternative Treatment of Transport in Magnetic Fields            | 383        |
| 24.3.8    | Magnetoresistance                                                | 384        |
| 24.4      | Transport Coefficients in Metals and Semiconductors              | 387        |
| 24.4.1    | Scattering of Electrons by Impurities                            | 387        |
| 24.4.2    | Contribution of Electron–Phonon Scattering<br>to the Resistivity | 389        |
| 24.4.3    | Scattering by Magnetic Impurities and the Kondo<br>Effect        | 394        |
| 24.4.4    | Electronic Contribution to Thermal Conductivity                  | 399        |
| 24.4.5    | Phonon Contribution to Thermal Conductivity                      | 400        |
| 24.4.6    | Transport Coefficients in Semiconductors                         | 402        |
| 24.5      | Quantum Hall Effect                                              | 405        |
| <b>25</b> | <b>Optical Properties of Solids</b>                              | <b>411</b> |
| 25.1      | Interaction of Solids with the Classical Radiation Field         | 412        |
| 25.1.1    | Propagation and Absorption of Light in a Dielectric              | 413        |
| 25.1.2    | Reflection and Refraction at an Interface                        | 417        |
| 25.1.3    | Role of Free and Bound Electrons                                 | 420        |
| 25.1.4    | Scattering of Light by Free Electrons                            | 421        |
| 25.1.5    | Reflectivity of Semiconductors                                   | 426        |
| 25.1.6    | Interaction of Light with Bound Electrons                        | 427        |
| 25.1.7    | Absorption and Dispersion in Ionic Crystals                      | 430        |

|           |                                                                               |            |
|-----------|-------------------------------------------------------------------------------|------------|
| 25.2      | Quantum Mechanical Treatment                                                  | 435        |
| 25.2.1    | Dielectric Constant of the System of Electrons                                | 435        |
| 25.2.2    | Electron–Photon Interaction                                                   | 440        |
| 25.2.3    | Phonon–Photon Interaction                                                     | 443        |
| <b>26</b> | <b>Superconductivity</b>                                                      | <b>449</b> |
| 26.1      | Superconductivity: The Phenomenon                                             | 451        |
| 26.1.1    | Vanishing Resistance, Persistent Current                                      | 451        |
| 26.1.2    | Isotope Effect                                                                | 452        |
| 26.1.3    | Meissner–Ochsenfeld Effect                                                    | 452        |
| 26.1.4    | Critical Field                                                                | 455        |
| 26.1.5    | Thermoelectric Properties                                                     | 457        |
| 26.1.6    | Specific Heat                                                                 | 458        |
| 26.1.7    | Tunneling in SIS and SIN Junctions                                            | 460        |
| 26.2      | Superconducting Materials                                                     | 461        |
| 26.2.1    | Superconducting Elements                                                      | 461        |
| 26.2.2    | Superconducting Compounds                                                     | 464        |
| 26.2.3    | High-Temperature Superconductors                                              | 466        |
| 26.3      | Phenomenological Description of Superconductivity                             | 469        |
| 26.3.1    | Thermodynamics of Superconductors                                             | 470        |
| 26.3.2    | Electrodynamics of Superconductors                                            | 474        |
| 26.3.3    | Pippard Coherence Length                                                      | 479        |
| 26.3.4    | Flux Quantization                                                             | 481        |
| 26.4      | Ginzburg–Landau Theory                                                        | 482        |
| 26.4.1    | Ginzburg–Landau Equations                                                     | 483        |
| 26.4.2    | Gauge Symmetry Breaking                                                       | 485        |
| 26.4.3    | Coherence Length and Penetration Depth                                        | 486        |
| 26.4.4    | Flux Quantization                                                             | 489        |
| 26.4.5    | Energy of the Normal Metal–Superconductor Interface                           | 491        |
| 26.4.6    | Vortices                                                                      | 493        |
| 26.4.7    | Upper and Lower Critical Fields                                               | 497        |
| 26.5      | Josephson Effect                                                              | 501        |
| 26.5.1    | Relation Between the Josephson Current and the Phase<br>of the Superconductor | 501        |
| 26.5.2    | DC Josephson Effect                                                           | 504        |
| 26.5.3    | AC Josephson Effect                                                           | 506        |
| 26.5.4    | Josephson Junctions in a Magnetic Field                                       | 509        |
| <b>27</b> | <b>Transport of Carriers in Semiconductor Devices</b>                         | <b>517</b> |
| 27.1      | Interfaces and Junctions                                                      | 518        |
| 27.1.1    | Metal–Semiconductor Interface                                                 | 518        |
| 27.1.2    | MOS Structures                                                                | 525        |
| 27.1.3    | $p$ – $n$ Junctions                                                           | 526        |
| 27.1.4    | Heterojunctions                                                               | 532        |

|          |                                                                            |            |
|----------|----------------------------------------------------------------------------|------------|
| 27.2     | Generation, Motion, and Recombination of Carriers . . . . .                | 533        |
| 27.2.1   | Generation and Recombination of Carriers . . . . .                         | 534        |
| 27.2.2   | Diffusion and Drift of Carriers . . . . .                                  | 537        |
| 27.2.3   | Fundamental Equations of the Physics of Semiconductor<br>Devices . . . . . | 540        |
| 27.3     | Biased Semiconductor Junctions . . . . .                                   | 541        |
| 27.3.1   | Biased Schottky Diodes . . . . .                                           | 541        |
| 27.3.2   | Biased MOS Structures . . . . .                                            | 545        |
| 27.3.3   | Current–Voltage Characteristics of $p$ – $n$ Junctions . . . . .           | 545        |
| 27.3.4   | Zener and Avalanche Breakdown in $p$ – $n$ Junctions . . . . .             | 554        |
| 27.3.5   | Tunnel Diodes . . . . .                                                    | 556        |
| 27.4     | Simple Semiconductor Devices . . . . .                                     | 558        |
| 27.4.1   | Bipolar Transistors . . . . .                                              | 558        |
| 27.4.2   | Field-Effect Transistors . . . . .                                         | 560        |
| 27.4.3   | Semiconductor Lasers and Solar Cells . . . . .                             | 562        |
| 27.5     | Semiconductor Quantum Devices . . . . .                                    | 564        |
| 27.5.1   | Electron Spectrum of Quantum Wells . . . . .                               | 565        |
| 27.5.2   | Quantum Wires and Quantum Dots . . . . .                                   | 567        |
| 27.6     | Basics of Spintronics . . . . .                                            | 573        |
| <b>G</b> | <b>Quantum Mechanical Perturbation Theory . . . . .</b>                    | <b>579</b> |
| G.1      | Time-Independent Perturbation Theory . . . . .                             | 579        |
| G.1.1    | Nondegenerate Perturbation Theory . . . . .                                | 579        |
| G.1.2    | Degenerate Perturbation Theory . . . . .                                   | 583        |
| G.2      | Time-Dependent Perturbation Theory . . . . .                               | 584        |
| <b>H</b> | <b>Second Quantization . . . . .</b>                                       | <b>589</b> |
| H.1      | Occupation-Number Representation . . . . .                                 | 589        |
| H.2      | Second-Quantized Form of Operators . . . . .                               | 593        |
| H.2.1    | Second-Quantized Form of One-Particle Operators . . . . .                  | 593        |
| H.2.2    | Second-Quantized Form of Two-Particle Operators . . . . .                  | 595        |
| H.2.3    | Field Operators . . . . .                                                  | 596        |
| H.2.4    | Second-Quantized Form of the Electronic Hamiltonian . . . . .              | 597        |
| H.2.5    | Number-Density and Spin-Density Operators . . . . .                        | 600        |
| <b>I</b> | <b>Canonical Transformation . . . . .</b>                                  | <b>603</b> |
| I.1      | Derivation of an Effective Hamiltonian . . . . .                           | 603        |
| I.1.1    | General Formulation of the Problem . . . . .                               | 603        |
| I.1.2    | RKKY Interaction . . . . .                                                 | 605        |
| I.1.3    | Derivation of the $s$ – $d$ Interaction . . . . .                          | 611        |
| I.2      | Diagonalization of the Hamiltonian . . . . .                               | 612        |
| I.2.1    | Bosonic Systems . . . . .                                                  | 613        |
| I.2.2    | Fermionic Systems . . . . .                                                | 615        |

XVIII Contents

|                             |     |
|-----------------------------|-----|
| <b>Figure Credits</b> ..... | 617 |
| <b>Name Index</b> .....     | 621 |
| <b>Subject Index</b> .....  | 625 |